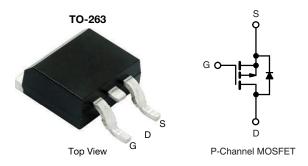


Automotive P-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	-100					
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0101					
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0150					
I _D (A)	-120					
Configuration	Single					
Package	TO-263					



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unless	otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	-100	V	
Gate-Source Voltage	V _{GS}	± 20	v		
Continuous Drain Current ^a	T _C = 25 °C ^a	1	-120		
	T _C = 125 °C	Ι _D	-78		
Continuous Source Current (Diode Conduct	ion) ^a	I _S	-120	А	
Pulsed Drain Current ^b		I _{DM}	-480		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	-78		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	304	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	PD	375	W	
	T _C = 125 °C	°C	125	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)		R _{thJC}	0.4	0/00	

Notes

a. Package limited.

b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

c. When mounted on 1" square PCB (FR4 material).

SQM120P10-10m1L



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static	-	-			-			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$		-100	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$		-1.5	-2.0	-2.5		
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -100 V	-	-	-1	μA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = -100 V, T _J = 125 °C	-	-	-50		
		$V_{GS} = 0 V$	V_{DS} = -100 V, T _J = 175 °C	-	-	-500		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 V$	-120	-	-	А	
		V _{GS} = -10 V	I _D = -30 A	-	0.0081	0.0101	Ω	
Durain Conversion On Otata Daviatana a	P	$V_{GS} = -10 \text{ V}$	I _D = -30 A, T _J = 125 °C	-	-	0.0168		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -30 A, T _J = 175 °C	-	-	0.0205		
		V _{GS} = -4.5 V	I _D = -20 A	-	0.0114	0.0150		
Forward Transconductance b	9 _{fs}	V _{DS} = -15 V, I _D = -25 A		-	60	-	S	
Dynamic ^b					•			
Input Capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	6750	9000	pF	
Output Capacitance	Coss	$V_{GS} = 0 V$		_	3500	5000		
Reverse Transfer Capacitance	C _{rss}			-	450	600		
Total Gate Charge ^c	Qg			-	125	190	nC	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -50 \text{ V}, I_D = -70 \text{ A}$	_	25	-		
Gate-Drain Charge ^c	Q _{gd}			-	30	-		
Gate Resistance	Rg	f = 1 MHz		3	6.44	9.7	Ω	
Turn-On Delay Time ^c	t _{d(on)}				20	30	ns	
Rise Time ^c	t _r	V_{DD} = -50 V, R _L = 0.71 Ω I _D \cong -70 A, V _{GEN} = -10 V, R _g = 1 Ω		-	100	150		
Turn-Off Delay Time ^c	t _{d(off)}			-	120	180		
Fall Time ^c	t _f			_	200	300		
Source-Drain Diode Ratings and Chara	acteristics ^b				•	•	•	
Pulsed Current ^a	I _{SM}			-	-	-480	A	
Forward Voltage	V _{SD}	I _F = -100 A, V _{GS} = 0 V		-	-0.95	-1.5	V	
Reverse Recovery Time ^b	t _{rr}			-	110	-	ns	
Reverse Recovery Charge b	Q _{rr}			-	385	-	nC	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2

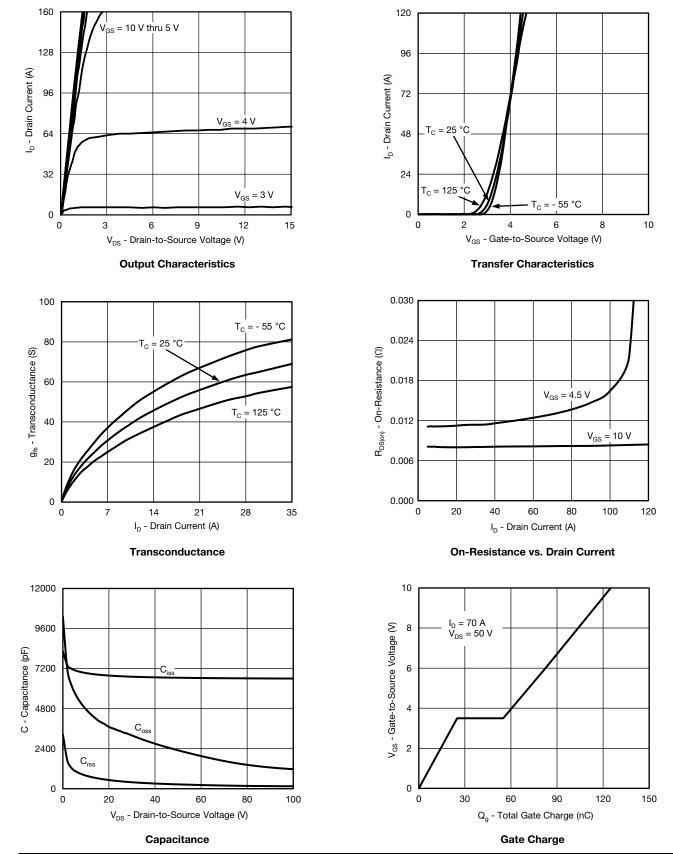
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



S15-2463-Rev. A, 19-Oct-15

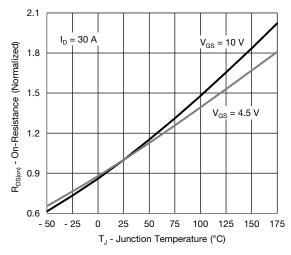
3

Document Number: 76943

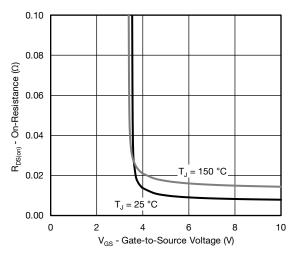
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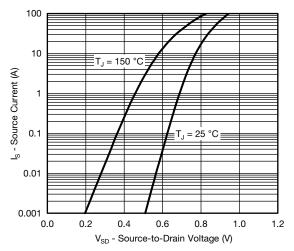
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



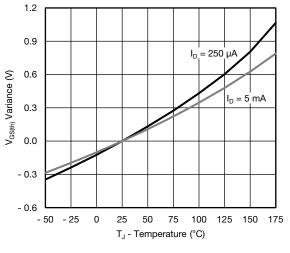
On-Resistance vs. Junction Temperature



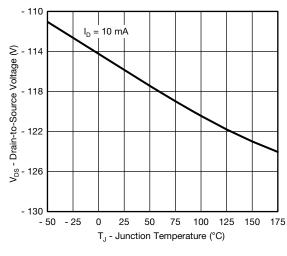
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature 4

Document Number: 76943

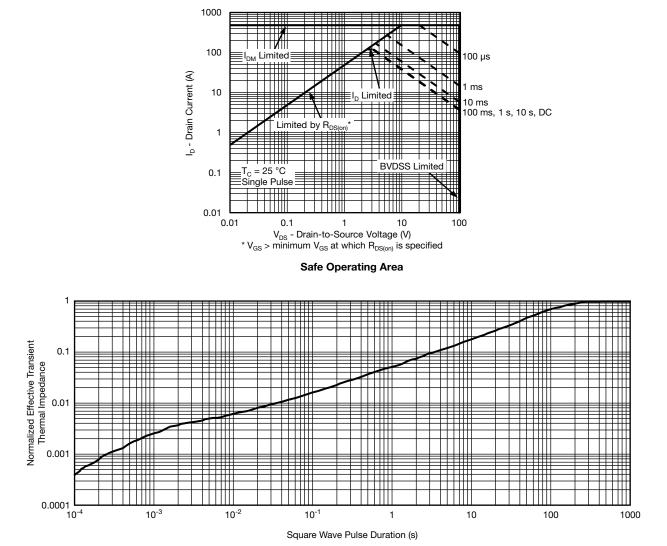
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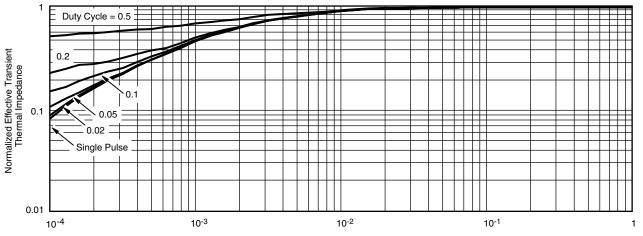
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Case

Note

· The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

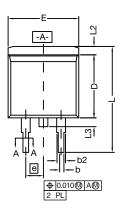
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

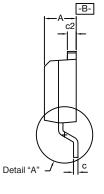
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

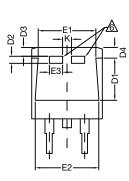
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TO-263 (D²PAK): 3-LEAD

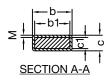








DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
	E3	0.072	0.072 0.078		1.981	
	е	0.100 BSC		2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

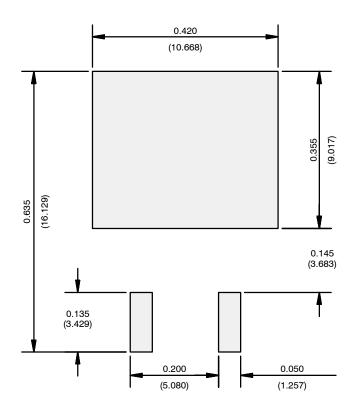
- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 $\,\%\,$ of L1 can fall above seating plane by
- max. 8 mils. 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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